

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

Product Specification

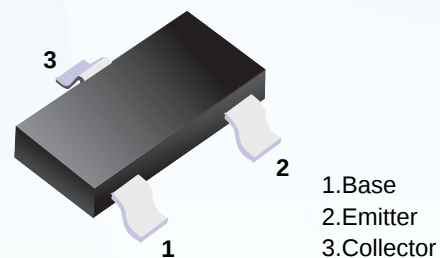
▶ Domestic	Part Number	MMBT4403
▶ Overseas	Part Number	MMBT4403
▶ Equivalent	Part Number	MMBT4403

EV is the abbreviation of name EVVO

PNP Transistors

Features

- Ideal for Medium Power Amplification and Switching
- Complementary NPN Type Available (MMBT4401)



■ Simplified outline(SOT-23)

Marking

Marking	2T
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Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

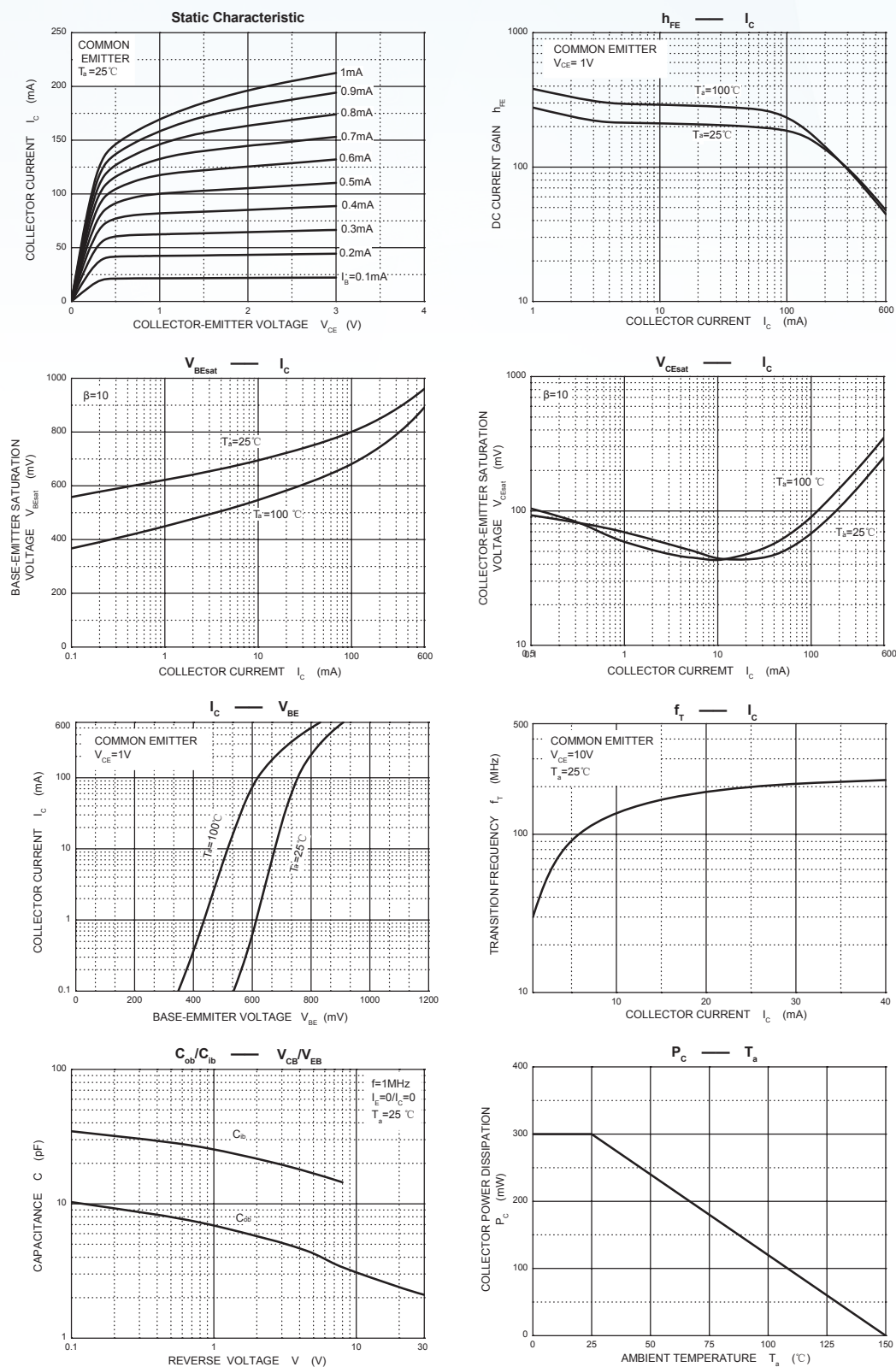
Parameter	Symbol	Rating	Unit
Collector-base voltage	V_{CB0}	-40	V
Collector-emitter voltage	V_{CE0}	-40	V
Emitter-base voltage	V_{EB0}	-5	V
Collector current	I_C	-600	mA
Total Device Dissipation Alumina Substrate	P_D	300	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to 150	$^\circ\text{C}$

Electrical Characteristics $T_a = 25^\circ\text{C}$

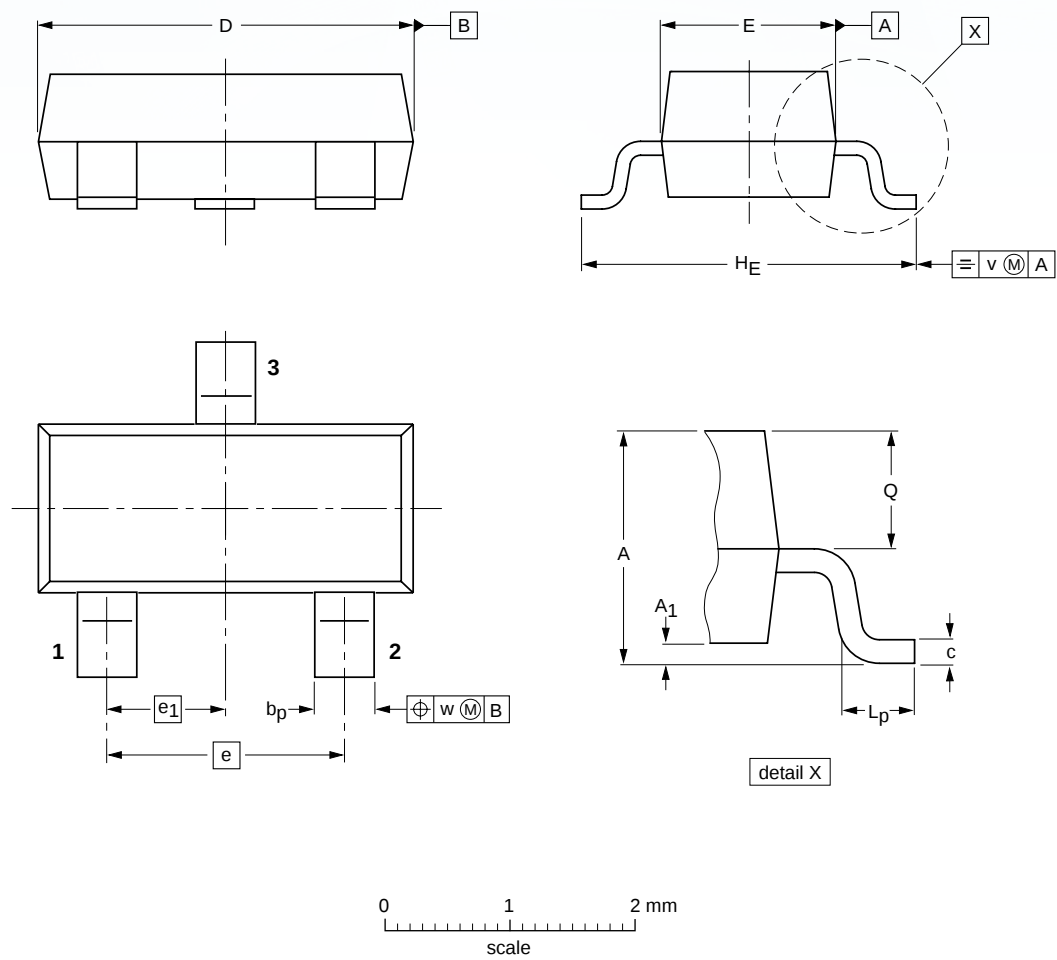
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}, I_E = 0$	-40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = 1.0\text{ mA}, I_B = 0$	-40			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = 100\mu\text{A}, I_C = 0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB} = -35\text{ V}, I_E = 0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -4\text{ V}, I_C = 0$			-0.1	μA
DC current gain *	h_{FE}	$I_C = -0.1\text{ mA}, V_{CE} = -1.0\text{ V}$ $I_C = -1.0\text{ mA}, V_{CE} = -1.0\text{ V}$ $I_C = -10\text{ mA}, V_{CE} = -1.0\text{ V}$ $I_C = -150\text{ mA}, V_{CE} = -2.0\text{ V}$ $I_C = -500\text{ mA}, V_{CE} = -2.0\text{ V}$	30 60 100 100 20		300	
Collector-emitter saturation voltage *	$V_{CE(sat)}$	$I_C = -150\text{ mA}, I_B = -15\text{ mA}$			-0.4	V
		$I_C = -500\text{ mA}, I_B = -50\text{ mA}$			-0.75	
Base-emitter saturation voltage *	$V_{BE(sat)}$	$I_C = 150\text{ mA}, I_B = 15\text{ mA}$	-0.75		-0.95	V
		$I_C = 500\text{ mA}, I_B = 50\text{ mA}$			-1.3	
Transition frequency	f_T	$I_C = 20\text{ mA}, V_{CE} = 10\text{ V}, f = 100\text{ MHz}$	200			MHz
Delay time	t_d	$V_{CC} = 30\text{ V}, V_{EB} = 2.0\text{ V},$			15	ns
Rise time	t_r	$I_C = 150\text{ mA}, I_{B1} = 15\text{ mA}$			20	ns
Storage time	t_s	$V_{CC} = 30\text{ V}, I_C = 150\text{ mA},$			225	ns
Fall time	t_f	$I_{B1} = I_{B2} = 15\text{ mA}$			30	ns

* Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2.0\%$.

■ Typical Characteristics



■ SOT-23



DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

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